Vishay General Semiconductor



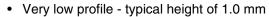
Low V_F High Current Density Surface Mount Schottky Barrier Rectifiers



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	1 A				
V _{RRM}	30 V, 40 V				
I _{FSM}	50 A				
E _{AS}	11.25 mJ				
V _F	0.35 V, 0.38 V				
T _J max.	150 °C				

FEATURES





· Ideal for automated placement

Low forward voltage drop, low power losses



COMPLIANT

High efficiency

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

MECHANICAL DATA

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2

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whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS1P3L	SS1P4L	UNIT	
Device marking code		13L	14L		
Maximum repetive peak reverse voltage	V _{RRM}	30	40	V	
Maximum average forward rectified current (Fig. 1) $T_L = 140 ^{\circ}\text{C}$ $T_L = 135 ^{\circ}\text{C}$	I _{F(AV)}	1.0 1.5		А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	ed on I _{FSM} 50			А	
Non-repetitive avalanche energy at $I_{AS} = 1.5 \text{ A}$, $L = 10 \text{ mH}$, $T_{J} = 25 ^{\circ}\text{C}$	E _{AS}	11.25		mJ	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150		°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	SS1P3L	SS1P4L	UNIT
Maximum instantaneous forward voltage (1)	I _F = 1.0 A I _F = 1.0 A	T _J = 25 °C T _J = 125 °C	V _F	0.45 0.35	0.48 0.38	V
Maximum reverse current at rated V _R ⁽²⁾		T _J = 25 °C T _J = 125 °C	I _R	200 20	150 15	μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	110	130	pF

Notes:

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS1P3L	SS1P4L	UNIT	
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL} R _{θJC}	105 15 20		°C/W	

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS1P3L-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS1P3L-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
SS1P3LHE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
SS1P3LHE3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note:

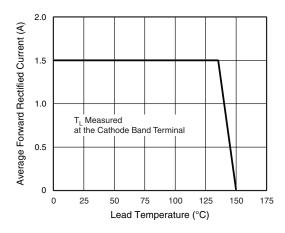
(1) Automotive grade AEC Q101 qualified

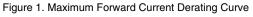
RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

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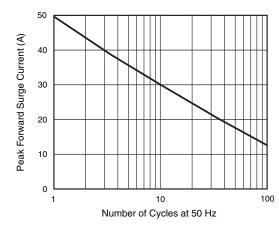


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

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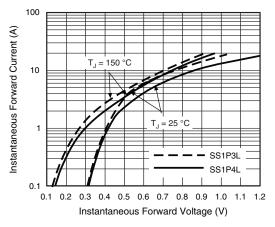


Figure 3. Typical Instantaneous Forward Characteristics

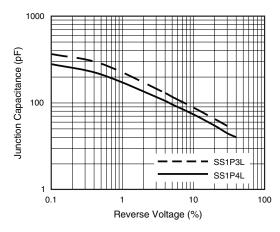


Figure 5. Typical Junction Capacitance

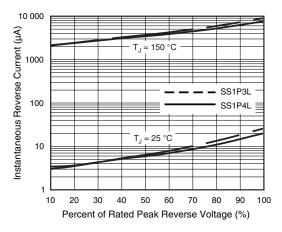


Figure 4. Typical Reverse Leakage Characteristics

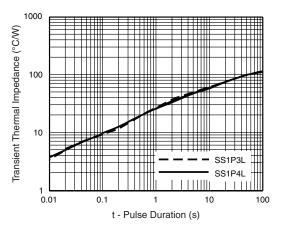
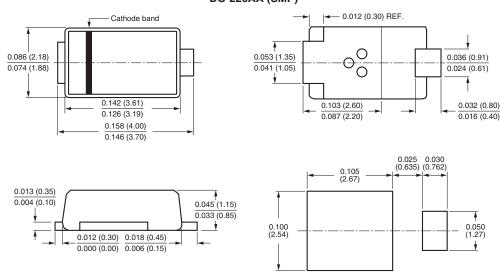


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)





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